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**IN THE UNITED STATES PATENT AND TRADEMARK OFFICE**

In re patent application of

Noboru ICHINOSE, et al.

Serial No.: 10/589,852

Group Art Unit: 2829

Filing Date: November 27, 2006

Examiner: Daniel B. Whalen

For: METHOD FOR CONTROLLING CONDUCTIVITY OF Ga<sub>2</sub>O<sub>3</sub> SINGLE CRYSTAL

Honorable Commissioner of Patents  
Alexandria, Virginia 22313-1450

**INFORMATION DISCLOSURE STATEMENT**

Sir:

Under the provisions of 37 CFR §1.97 through §1.98 and pursuant to Applicant's duty of disclosure under 37 CFR §1.56, Applicant respectfully brings the following Japanese Office Action to the attention of the Examiner in charge of the above-identified application.

In compliance with the concise explanation requirement under 37 CFR §1.98(a)(3) for foreign language documents, Applicant encloses herewith a copy of the Japanese Office Action, together with an English-language version (if not already included) of that portion of the Office Action indicating the degree of relevance found by the foreign office.

I hereby certify that each item of information contained in this Information Disclosure Statement was the first citation of that item by a foreign patent office in a counterpart foreign application, which occurred not more than three months prior to the filing of this statement.

It is respectfully requested that the Japanese Office Action be considered by the Examiner and formally made of record in this application.

U.S. Application Serial No.: 10/589,852  
PKHF-05004US  
(HIR.228)

Please charge any deficiencies in fees and credit any overpayment of fees to  
Attorney's Deposit Account No. 50-0481.

Respectfully submitted,



Christopher R. Monday, Esq.  
Registration No. 60,929  
Sean M. McGinn, Esq.  
Registration No. 34,386

Date: June 4 2003  
**MCGINN INTELLECTUAL PROPERTY  
LAW GROUP, PLLC**  
8321 Old Courthouse Road, Suite 200  
Vienna, Virginia 22182-3817  
(703) 761-4100  
Customer No. 21254